Thyristor Semiconductor Device - Page 1 of 1

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## Inclosure Material:

Metal
Overall Length:
0.185 inches

Terminal Length:
0.365 inches

Overall Diameter:
0.430 inches

Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches

Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 repetitive peak reverse voltage, peak total value

Current Rating Per Characteristic:
8.00 amperes forward current, dc

Power Rating Per Characteristic:
0.5 watts small-signal input power, common-collector peak

Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction

## Test Data Document:

17863-7117140 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
3 insulated wire lead w/terminal lug
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:
A110a0

